



T1610H-8F 16A TRIAC

Rev.A.1.1

DESCRIPTION:

The T1610H-8F triac i

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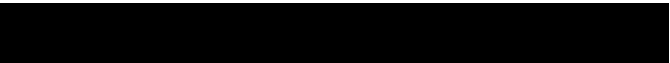
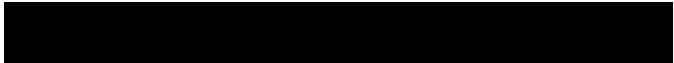
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Peak gate current ($t_p=20\mu s$, $T_j=150$)	I_{GM}	4	A
Average gate power dissipation ($T_j=150$)	$P_{G(AV)}$		





ORDERING INFORMATION

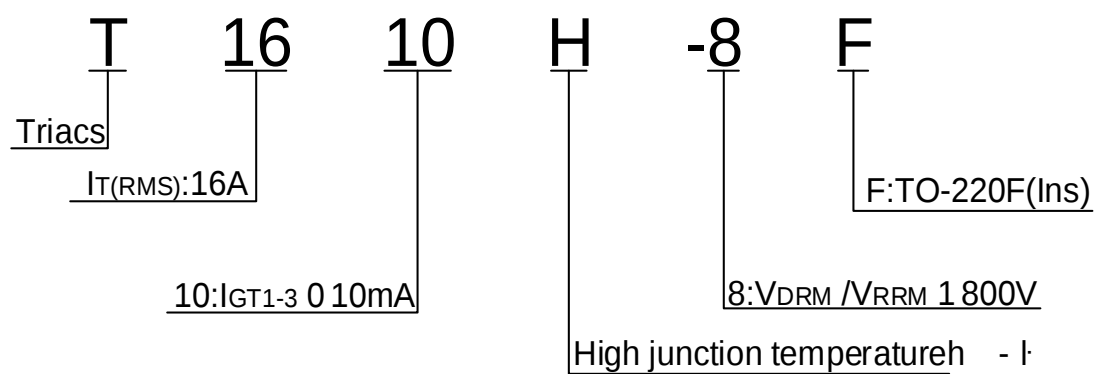




FIG.1: Maximum power dissipation versus RMS on-state current

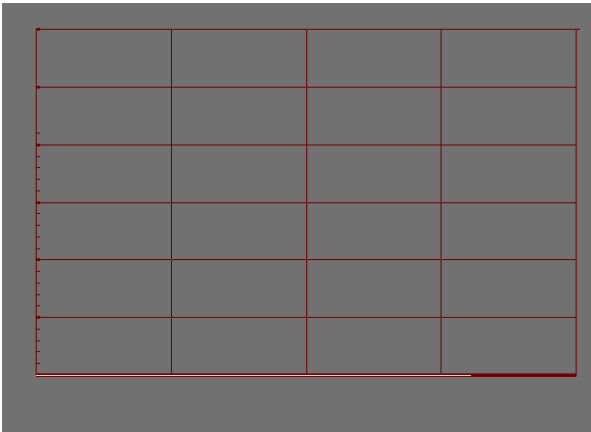


FIG.2: RMS on-state current versus case temperature



FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards



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